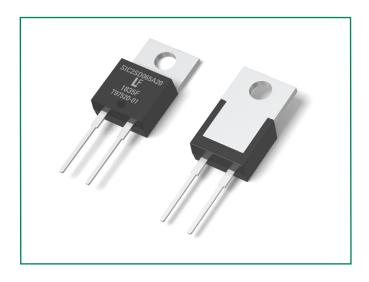


LSIC2SD065A20A 650 V, 20 A SiC Schottky Barrier Diode









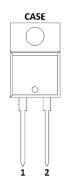
Description

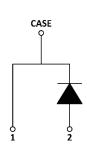
This series of silicon carbide (SiC) Schottky diodes has negligible reverse recovery current, high surge capability, and a maximum operating junction temperature of 175 °C. These diodes series are ideal for applications where improvements in efficiency, reliability, and thermal management are desired.

Features

- AEC-Q101 qualified
- Positive temperature coefficient for safe operation and ease of paralleling
- 175 °C maximum operating junction temperature
- Excellent surge capability
- Extremely fast, temperature-independent switching behavior
- Dramatically reduced switching losses compared to Si bipolar diodes

Circuit Diagram TO-220-2L





Applications

- Boost diodes in PFC or DC/DC stages
- Switch-mode power supplies
- Uninterruptible power supplies
- Solar inverters
- Industrial motor drives
- EV charging stations

Environmental

- Littelfuse "RoHS" logo = RoHS RoHS conform
- Littelfuse "HF" logo = HF Halogen Free
- Littelfuse "Pb-free" logo = P Pb-free lead plating

Maximum Ratings

Characteristics	Symbol	Conditions	Value	Unit	
Repetitive Peak Reverse Voltage	V _{RRM}	-	650	V	
DC Blocking Voltage	V _R	T _J = 25 °C	650	V	
Continuous Forward Current	I _F	T _c = 25 °C	45	А	
		T _C = 135 °C	20		
Non-Repetitive Forward Surge Current	I _{FSM}	$T_{\rm C} = 25 {\rm ^{\circ}C}$, $T_{\rm P} = 10 {\rm ms}$, Half sine pulse	90	А	
Power Dissipation	P _{Tot}	T _c = 25 °C	135	W	
		T _C = 110 °C	60	VV	
Operating Junction Temperature	T _J	-	-55 to 175	°C	
Storage Temperature	T _{STG}	-	-55 to 150	°C	
Soldering Temperature	T _{SOLD}	-	260	°C	

GEN2 SiC Schottky Diode LSIC2SD065A20A, 650 V, 20 A, TO-220-2L

Electrical Characteristics (T₁ =25 °C unless otherwise specified)

	Symbol Conditions	Value				
Characteristics		Conditions	Min.	Тур.	Max.	Unit
Forward Voltage	V _F	I _F = 20 A, T _J = 25 °C	-	1.5	1.8	V
		I _F = 20 A, T _J = 175 °C	-	1.85	-	
Reverse Current	I _R	$V_{R} = 650 V$, $T_{J} = 25 ^{\circ}C$	-	<1	50	μА
		$V_{R} = 650 \text{V}, T_{J} = 175 ^{\circ}\text{C}$	-	60	-	
Total Capacitance	С	V _R = 1 V, f = 1 MHz	-	960	-	pF
		$V_{R} = 200 V, f = 1 MHz$	-	120	-	
		V _R = 400 V, f = 1 MHz	-	86	-	
Total Capacitive Charge	O _c	$V_{R} = 400 \text{ V}, \ \ Q_{C} = \int\limits_{0}^{V_{R}} C(V) dV$	-	63	-	nC

Thermal Characteristics					
Characteristics	Symbol	Value	Unit		
Thermal Resistance	R _{aic}	1.1	°C/W		

Figure 1: Typical Foward Characteristics

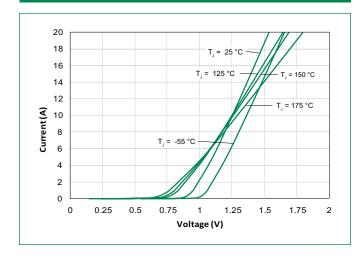


Figure 2: Typical Reverse Characteristics

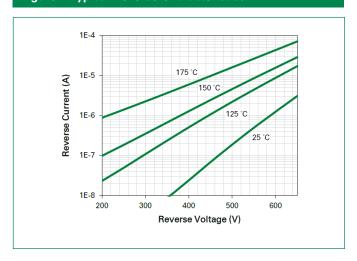




Figure 3: Power Derating

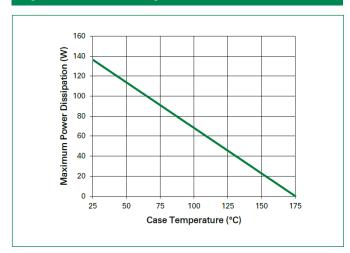


Figure 4: Current Derating

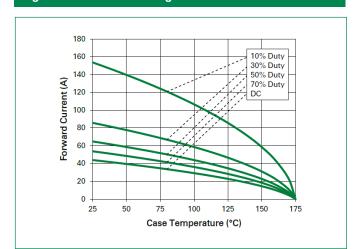


Figure 5: Capacitance vs. Reverse Voltage

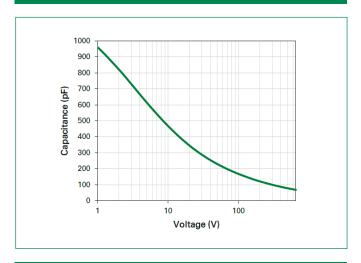


Figure 6: Capacitive Charge vs. Reverse Voltage

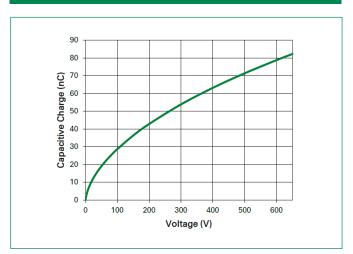


Figure 7: Stored Energy vs. Reverse Voltage

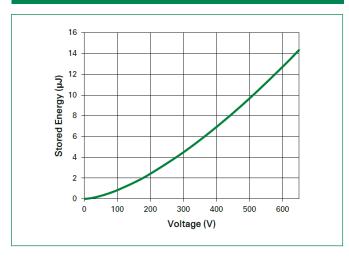
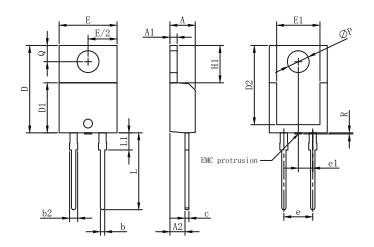


Figure 8: Transient Thermal Impedance

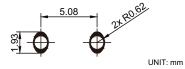


GEN2 SiC Schottky Diode LSIC2SD065A20A, 650 V, 20 A, TO-220-2L

Dimensions-Package TO-220-2L

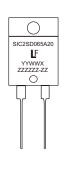


Recommended Solder Pad Layout



Cymahal		Millimeters	
Symbol	Min	Nom	Max
А	4.32	4.45	4.70
A1	1.14	1.27	1.40
A2	2.20	-	2.74
b	0.69	-	0.90
b2	1.17	-	1.62
С	0.36	-	0.60
D	14.90	-	15.90
D1	8.62	-	9.40
D2	12.50	-	12.95
Е	9.70	10.18	10.36
E1	7.57	7.61	8.30
e1	-	2.54	-
е	5.03	5.08	5.13
H1	6.30	6.55	6.80
L	12.88	13.50	14.00
L1	2.39	-	3.25
øΡ	3.50	3.84	3.96
Q	2.65	-	3.05
R	-	-	0.25

Part Numbering and Marking System



SIC	= SiC Diode
	0.0 5.000
2	= Gen2
SD	= Schottky Diode
065	= Voltage Rating (650 V)
Α	= TO-220 Package (2 Lead)
20	= Current Rating (20 A)
YY	= Year
WW	= Week
X	= Special Code
ZZZZZZ-ZZ	= Lot Number

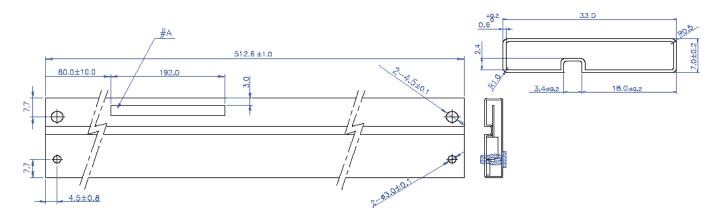
Packing Options

Part Number	Marking	Packing Mode	M.O.Q
LSIC2SD065A20A	SIC2SD065A20	Tube(50pcs)	1000



GEN2 SiC Schottky Diode LSIC2SD065A20A, 650 V, 20 A, TO-220-2L

Packing Specification (Tube for TO-220-2L)



[NOTE]

- 1. TUBE MATERIAL : PVC / PET (WITH ANTISTATIC COATING)
 - COLOR: TRANSPARENCY, RED, YELLO
 - MARKING #A : BLACK COLOR, LETTER STYLE : Arial
 - Tube Surface Resistance $:10^6 \sim 10^{11} \,\Omega\,/\text{square}$
 - ESD (Electro Static Discharge) : less than 100 [volts], 6 Months
 - CAMBAR : 1.5 MAX
- 2. PIN COLOR : GREEN (ONE PIN MUST BE INSERTED IN LEFT-SIDE OF " \square ANTISTATIC~" AND ANOTHER PIN IS FREE.)

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